POINT CONTACT GERMANIUM DIODE

The germanium point contact (Ge) diodes are widely used For detecting the rectifying efficiency or for switching on the radio, TV, or stereo, ect.

Features

- · High reliability for resistance to vibration and shock proof.
- · High withstand voltage.
- · Small reverse current.
- Excellent electrical characteristics suitable for FM. detection or MPX.

max. \$60. 5

Glass case JEDEC DO-7

Dimensions in mm

Application

 FM detection, MPX, projected-image detection. switching, and limiter

Absolute Maximum Ratings (T_a = 25°C)

	Symbol	Value	Unit
Peak Reverse Voltage	V _{RM}	45	V
Reverse Voltage dc	V _R	20	V
Peak Forward Current	I _{FM}	150	mA
Average Rectified Output Current	I _O	50	mA
Surge Forward Current	I _{surge}	500	mA
Junction Temperature	Tj	75	°C
Storage Temperature Range	Ts	-55 to +75	°C

Characteristics (1N34A)

	Symbol	Test condition(Ta25± 2°C)	Min.	Тур.	Max.	Unit
Forward voltage	IF	V _F =1V	4	2	-	mA
Reverse currents	I _R	V _R =-10V	-	-	100	μА
	I _{R2}	V _R =V	-	-	-	μА
Junction Capacitance Cj	-	f=1MHz, V=-1V	-	-	1	pF
Rectification efficiency	η	Vi=2Vrms,=50KΩ C=20PF, f=40MHz	55	-	-	%

0.018-0.022

0.458-.558 mm

0.085-.107 "

DO-7 Glass Package

Length

0.230-0.30" 5.85-7.62mm

Optimized for Radio Frequency Response

Can be used in many AM, FM and TV-IF applications, replacing point contact devices.

25.4 mm

(Min.)

Applications

- AM/FM detectors
- Ratio detectors
- FM discriminators
- TV audio detectors
- RF input probes
- TV video detectors

Features

- Lower leakage current
- Flat junction capacitance
- High mechanical strength
- At least 1 million hours MTBF
- BKC's Sigma-Bond™ plating for

problem free solderability

Absolute Maximum Ratings at T_{amb} = 25 °C

Symbols	Min.	Max.	Units
PIV	**	65	Volts
I		0.5	Amps
i i		200	mΑ
ì		50	mΑ
TJ&STG	-55	+75	°C
	PIV I _{FSM} I _{FSR} I _O	PIV **	PIV ** 65 I _{FSM} 0.5 I _{FSR} 200 I _O 50

Parameter	TestConditions	Symbols	Min.	Max.	Units
Forward Voltage Drop	I _F = 5.0mA	V _F		1.0	Volts
	V _R = 10 Volts			30	μA
Reverse Leakage	V _R = 50 Volts	I _R		500	μΑ
Breakdown Voltage	Ir = 1.0 mA	PIV	65		Volts